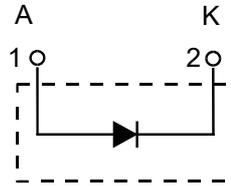
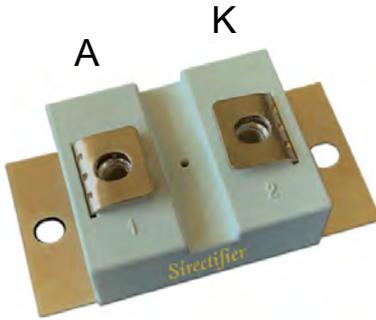
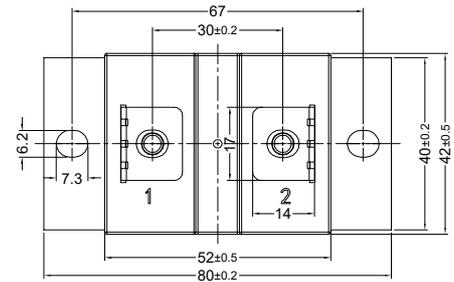
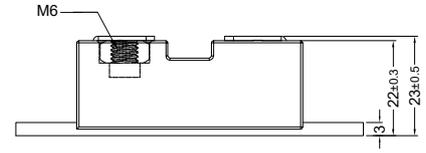


SDF300-05D4

Soft Recovery Behaviour Ultra Fast Recovery Epitaxial Diode Modules



Dimensions in mm



| | V_{RSM} V | V_{RRM} V |
|--------------------|----------------|----------------|
| SDF300-05D4 | 500 | 500 |
| SDF300-06D4 | 600 | 600 |
| SDF300-07D4 | 700 | 700 |

| Symbol | Test Conditions | Maximum Ratings | Unit |
|-----------------------|---|------------------------------------|----------------------|
| I_{FRMS} | $T_C=115^\circ\text{C}$ | 424 | A |
| I_{FAVM} | $T_C=115^\circ\text{C}$; rectangular, $d=0.5$ $t_p < 10\mu\text{s}$ | 300 | |
| I_{FRM} | rep. rating, pulse width limited by T_{VJM} | 1560 | |
| I_{FSM} | $T_{VJ}=45^\circ\text{C}$ $t=10\text{ms}(50\text{HZ}), \text{sine}$ $t=8.3\text{ms}(60\text{HZ}), \text{sine}$ | 4100 4470 | A |
| | $T_{VJ}=150^\circ\text{C}$ $t=10\text{ms}(50\text{HZ}), \text{sine}$ $t=8.3\text{ms}(60\text{HZ}), \text{sine}$ | 3690 4020 | |
| I^2t | $T_{VJ}=45^\circ\text{C}$ $t=10\text{ms}(50\text{HZ}), \text{sine}$ $t=8.3\text{ms}(60\text{HZ}), \text{sine}$ | 81700 82100 | A^2s |
| | $T_{VJ}=150^\circ\text{C}$ $t=10\text{ms}(50\text{HZ}), \text{sine}$ $t=8.3\text{ms}(60\text{HZ}), \text{sine}$ | 66400 73800 | |
| T_{VJ} T_{stg} | | -40...+150 -40...+125 | $^\circ\text{C}$ |
| V_{ISOL} | 50/60Hz, RMS $t=1\text{min}$ $I_{ISOL} \leq 1\text{mA}$ $t=1\text{s}$ | 2500 3000 | V~ |
| M_d | Mounting torque(M6) Terminal connection torque(M6) | 2.25-2.75/20-25 4.50-5.50/40-48 | Nm/lb.in. |
| d_s | Creeping distance on surface | 12.7 | mm |
| d_A | Strike distance through air | 9.6 | mm |
| a | Maximum allowable acceleration | 50 | m/s^2 |
| Weight | | 165 | g |

SDF300-06D4

Soft Recovery Behaviour Ultra Fast Recovery Epitaxial Diode Modules

| Symbol | Test Conditions | Characteristic Values | | Unit |
|--------------------------|---|-----------------------|------------------|------------|
| | | typ. | max. | |
| I_R | $T_{VJ}=25^{\circ}\text{C}; V_R=V_{RRM}$ $T_{VJ}=25^{\circ}\text{C}; V_R=0.8 \cdot V_{RRM}$ $T_{VJ}=125^{\circ}\text{C}; V_R=0.8 \cdot V_{RRM}$ | | 0.5 0.5 30 | mA |
| V_F | $I_F=300\text{A}; T_{VJ}=125^{\circ}\text{C}$ $T_{VJ}=125^{\circ}\text{C}$ | 1.10 1.20 | 1.25 1.30 | V |
| V_{FO} | For power-loss calculations only | | 0.85 | V |
| r_F | | | 1.09 | m Ω |
| R_{thJH} R_{thJC} | DC current DC current | | 0.195 0.162 | K/W |
| t_{tr} | $I_F=1\text{A}; V_R=250\text{V}; -di/dt=200\text{A}/\mu\text{s}; T_{VJ}=25^{\circ}\text{C}$ | 75 | | ns |
| t_{tr} I_{RM} | $I_F=300\text{A}; V_R=250\text{V}; -di/dt=200\text{A}/\mu\text{s}; T_{VJ}=125^{\circ}\text{C}$ | 430 35 | | ns A |

FEATURES

- * International standard package
- * Copper base plate
- * Planar passivated chips
- * Soft recovery behaviour
- * Isolation voltage 3000V~
- * ROHS compliant

APPLICATIONS

- * Antiparallel diode for high frequency switching devices
- * Free wheeling diode in converters and motor control circuits
- * Inductive heating and melting
- * Uninterruptible power supplies(UPS)
- * Ultrasonic cleaners and welders
- * Inverter Welding Application

ADVANTAGES

- * High reliability circuit operation
- * Low voltage peaks for reduced protection circuits
- * Low noise switching
- * Low losses

SDF300-06D4

Soft Recovery Behaviour Ultra Fast Recovery Epitaxial Diode Modules

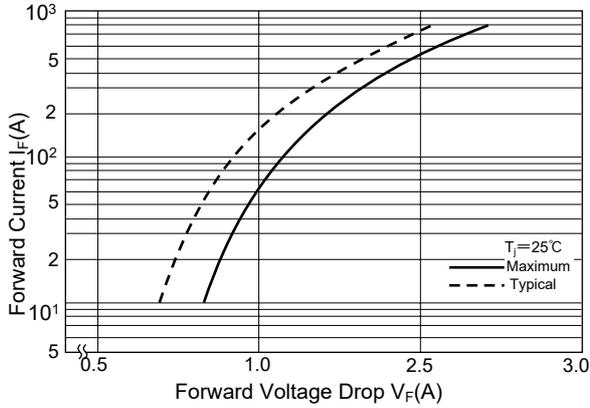


Fig.1 Forward Characteristics

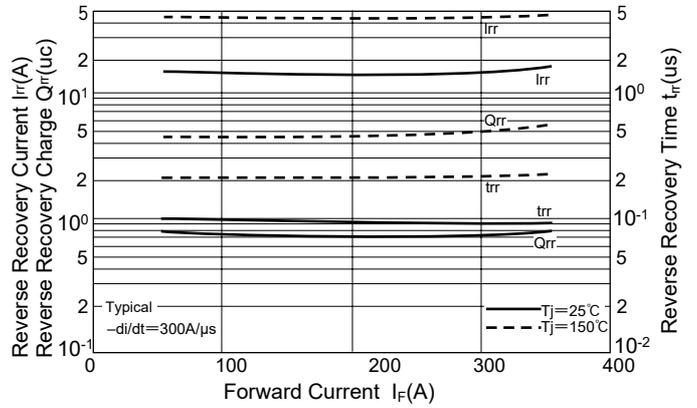


Fig.2 Reverse Recovery Characteristics

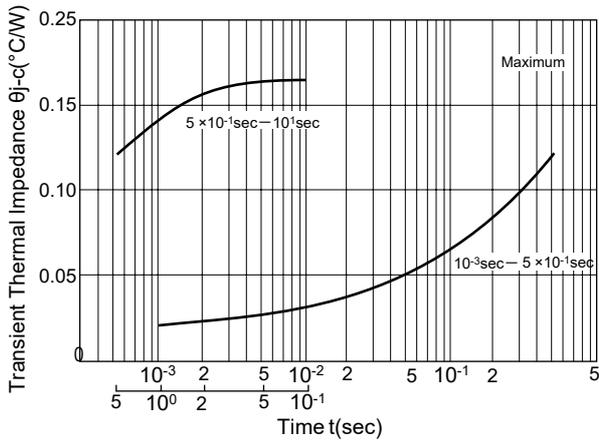


Fig.3 Transient Thermal Impedance

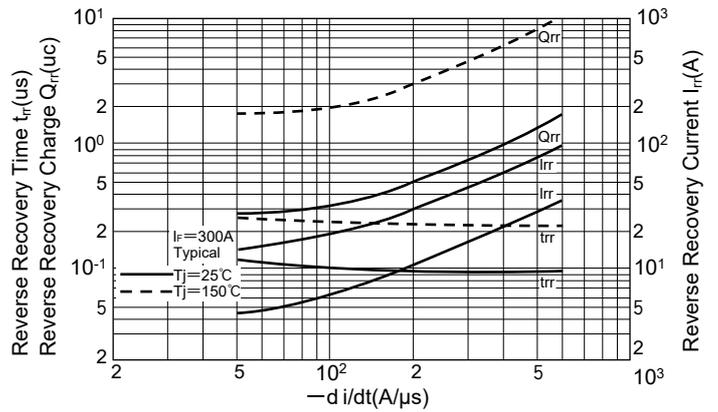


Fig.4 Reverse Recovery Characteristics